# Low Power, Rail-to-Rail Output Precision JFET Amplifier

# AD8641/AD8642/AD8643

## FEATURES

**Low supply current: 250 µA max**
**Very low input bias current: 1 pA max**
**Low offset voltage: 750 µV max**
**Single-supply operation: 5 V to 26 V**
**Dual-supply operation: ±2.5 V to ±13 V**
**Rail-to-rail output**
**Unity-gain stable**
**No phase reversal**
**SC70 package**

## APPLICATIONS

**Line-/battery-powered instruments**
**Photodiode amplifiers**
**Precision current sensing**
**Medical instrumentation**
**Industrial controls**
**Precision filters**
**Portable audio**
**ATE**



## GENERAL DESCRIPTION

The AD8641/AD8642/AD8643 are low power, precision JFET input amplifiers featuring extremely low input bias current and rail-to-rail output. The ability to swing nearly rail-to-rail at the input and rail-to-rail at the output enables designers to buffer CMOS DACs, ASICs, and other wide output swing devices in single-supply systems. The outputs remain stable with capacitive loads of more than 500 pF.

The AD8641/AD8642/AD8643 are suitable for applications utilizing multichannel boards that require low power to manage heat. Other applications include photodiodes, ATE reference level drivers, battery management, and industrial controls.

The AD8641/AD8642/AD8643 are fully specified over the extended industrial temperature range of –40°C to +125°C. The AD8641 is available in 5-lead SC70 and 8-lead SOIC lead-free packages. The AD8642 is available in 8-lead MSOP and 8-lead SOIC lead-free packages. The AD8643 is available in 14-lead SOIC and 16-lead, 3 mm × 3 mm, LFCSP lead-free packages.

## PIN CONFIGURATIONS

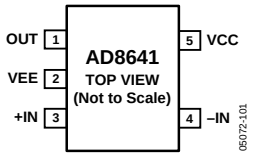


*Figure 1. 5-Lead SC70 (KS-5)*

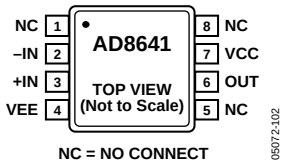


*Figure 2. 8-Lead SOIC (R-8)*

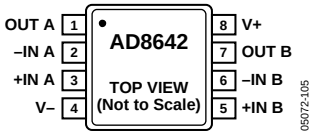


*Figure 3. 8-Lead SOIC (R-8)*

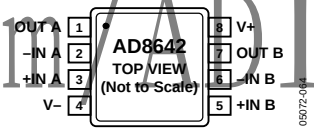


*Figure 4. 8-Lead MSOP (RM-8)*

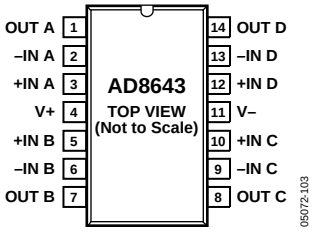


*Figure 5. 14-Lead SOIC (R-14)*

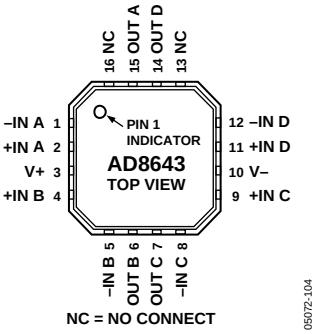


*Figure 6. 16-Lead LFCSP (CP-16) (Not Drawn to Scale)*

**Rev. B**



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## REVISION HISTORY

**4/05—Rev. A to Rev. B**

Added AD8643 ..... Universal
Added 14-Lead SOIC ..... Universal
Added 16-Lead LFCSP ..... Universal
Updated Outline Dimensions ..... 13
Changes to Ordering Guide ..... 14

**3/05—Rev. 0 to Rev. A**

Added AD8642 ..... Universal
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Updated Outline Dimensions ..... 13
Changes to Ordering Guide ..... 14

**10/04—Initial Version: Revision 0**

# SPECIFICATIONS

## ELECTRICAL CHARACTERISTICS

@ $V_S$ = 5.0 V, $V_{CM}$ = 2.5 V, $T_A$ = 25°C, unless otherwise noted.

**Table 1.**

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | $V_{OS}$ | | | 50 | 750 | µV |
| | | AD8643 LFCSP only | | | 1 | mV |
| | | –40°C < $T_A$ < +85°C | | | 1.5 | mV |
| | | +85°C < $T_A$ < +125°C, $V_{CM}$ = 1.5 V | | | 1.6 | mV |
| Input Bias Current | $I_B$ | | | 0.25 | 1 | pA |
| | | –40°C < $T_A$ < +125°C | | | 180 | pA |
| Input Offset Current | $I_{OS}$ | | | | 0.5 | pA |
| | | –40°C < $T_A$ < +125°C | | | 60 | pA |
| Input Voltage Range | | | 0 | | 3 | V |
| Common-Mode Rejection Ratio | CMRR | $V_{CM}$ = 0 V to 2.5 V | 74 | 93 | | dB |
| Large Signal Voltage Gain | $A_{VO}$ | $R_L$ = 10 kΩ, $V_O$ = 0.5 to 4.5 V | 80 | 140 | | V/mV |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | –40°C < $T_A$ < +125°C | | 2.5 | | µV/°C |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | $V_{OH}$ | | 4.95 | | | V |
| | | $I_L$ = 1 mA, –40°C to +125°C | 4.94 | | | V |
| Output Voltage Low | $V_{OL}$ | | | | 0.05 | V |
| | | $I_L$ = 1 mA, –40°C to +125°C | | 0.01 | 0.05 | V |
| Output Current | $I_{OUT}$ | | | ±6 | | mA |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_S$ = 5 V to 26 V | 90 | 107 | | dB |
| Supply Current/Amplifier | $I_{SY}$ | | | 195 | 250 | µA |
| | | –40°C < $T_A$ < +125°C | | | 270 | µA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | | | 2 | | V/µs |
| Gain Bandwidth Product | GBP | AD8641, AD8642 | | 3 | | MHz |
| | | AD8643 | | 2.5 | | MHz |
| Phase Margin | $Ø_m$ | | | 50 | | Degrees |
| NOISE PERFORMANCE | | | | | | |
| Voltage Noise | $e_N$ p-p | f = 0.1 Hz to 10 Hz | | 4.0 | | µV p-p |
| Voltage Noise Density | $e_N$ | f = 1 kHz | | 28.5 | | nV/√Hz |
| Current Noise Density | $i_N$ | f = 1 kHz | | 0.5 | | fA/√Hz |

@ $V_S$= ±13 V, $V_{CM}$ = 0 V, $T_A$ =25°C, unless otherwise noted.

**Table 2.**

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | $V_{OS}$ | | | 70 | 750 | µV |
| | | AD8643 LFCSP only | | | 1 | mV |
| | | −40° < $T_A$ < +125°C | | | 1.5 | mV |
| Input Bias Current | $I_B$ | | | 0.25 | 1 | pA |
| | | −40°C < $T_A$ < +125°C | | | 260 | pA |
| Input Offset Current | $I_{OS}$ | | | | 0.5 | pA |
| | | −40°C < $T_A$ < +125°C | | | 65 | pA |
| Input Voltage Range | | | −13 | | +10 | V |
| Common-Mode Rejection Ratio | CMRR | $V_{CM}$ = −13 V to +10 V | 90 | 107 | | dB |
| Large Signal Voltage Gain | $A_{VO}$ | $R_L$ = 10 kΩ, $V_O$ = −11 V to +11 V | 215 | 290 | | V/mV |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | −40°C < $T_A$ < +125°C | | 2.5 | | µV/°C |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | $V_{OH}$ | | +12.95 | | | V |
| | | $I_L$ = 1 mA, −40°C to +125°C | +12.94 | | | V |
| Output Voltage Low | $V_{OL}$ | | | | −12.95 | V |
| | | $I_L$ = 1 mA, −40°C to +125°C | | | −12.94 | V |
| Output Current | $I_{OUT}$ | | | ±12 | | mA |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_S$ = ±2.5 V to ±13 V | 90 | 107 | | dB |
| Supply Current/Amplifier | $I_{SY}$ | | | 200 | 290 | µA |
| | | −40°C < $T_A$ < +125°C | | | 330 | µA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | | | 3 | | V/µs |
| Gain Bandwidth Product | GBP | | | 3.5 | | MHz |
| Phase Margin | $Ø_m$ | | | 60 | | Degrees |
| NOISE PERFORMANCE | | | | | | |
| Voltage Noise | $e_N$ p-p | f = 0.1 Hz to 10 Hz | | 4.2 | | µV p-p |
| Voltage Noise Density | $e_N$ | f = 1 kHz | | 27.5 | | nV/√Hz |
| Current Noise Density | $i_N$ | f = 1 kHz | | 0.5 | | fA/√Hz |

# ABSOLUTE MAXIMUM RATINGS

**Table 3.**[1]

| Parameter | Rating |
|---|---|
| Supply Voltage | 27.3 V |
| Input Voltage | VS– to VS+ |
| Differential Input Voltage | ±Supply Voltage |
| Output Short-Circuit Duration | Indefinite |
| Storage Temperature Range | |
| KS-5, R-8, RM-8, R-14, CP-16 Packages | –65°C to +150°C |
| Operating Temperature Range | –40°C to +125°C |
| Junction Temperature Range | |
| KS-5, R-8, RM-8, R-14, CP-16 Packages | –65°C to +150°C |
| Lead Temperature Range (Soldering, 60 sec) | 300°C |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Table 4.**

| Package Type | $\theta_{JA}$[2] | $\theta_{JC}$ | Unit |
|---|---|---|---|
| 5-Lead SC70 (KS) | 331.4 | 223.9 | °C/W |
| 8-Lead SOIC (R) | 157 | 56 | °C/W |
| 8-Lead MSOP (RM) | 206 | 44 | °C/W |
| 14-Lead SOIC (R) | 120 | 36 | °C/W |
| 16-Lead LFCSP (CP) | 44 | 31.5 | °C/W |

[1] Absolute maximum ratings apply at 25°C, unless otherwise noted.
[2] $\theta_{JA}$ is specified for the worst-case conditions, that is, $\theta_{JA}$ is specified for devices soldered on circuit boards for surface-mounted packages.



## ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

# TYPICAL PERFORMANCE CHARACTERISTICS

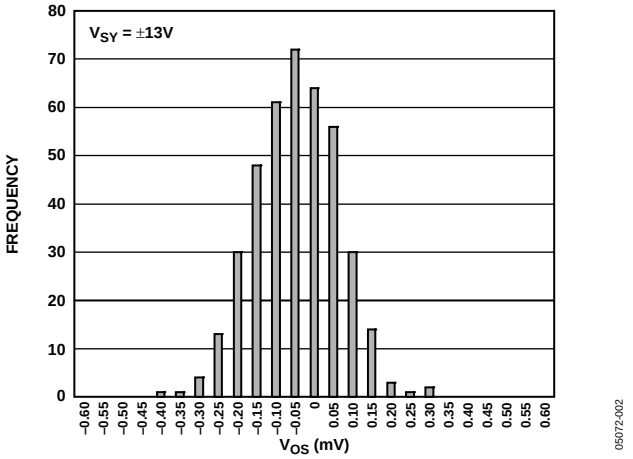



Figure 7. Input Offset Voltage

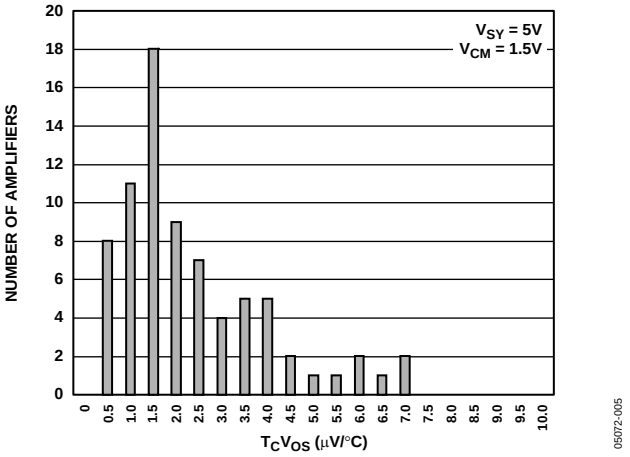



Figure 10. Offset Voltage Drift

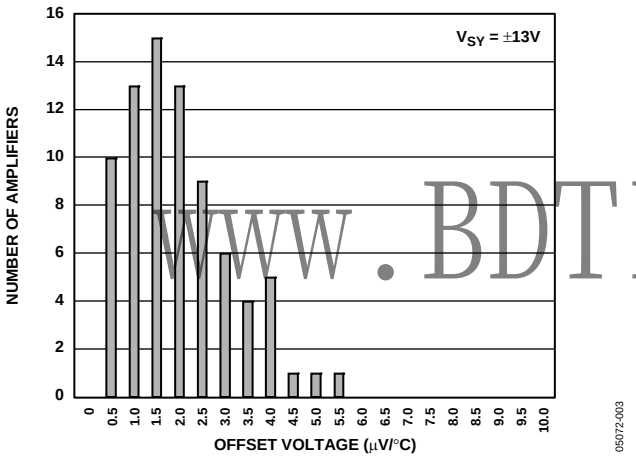



Figure 8. Offset Voltage Drift

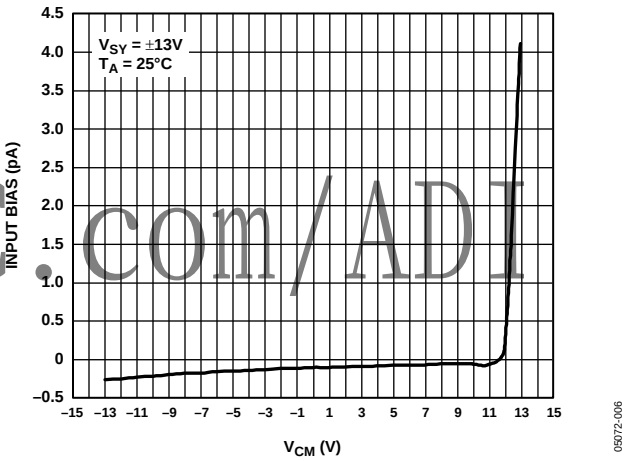



Figure 11. Input Bias Current vs. $V_{CM}$



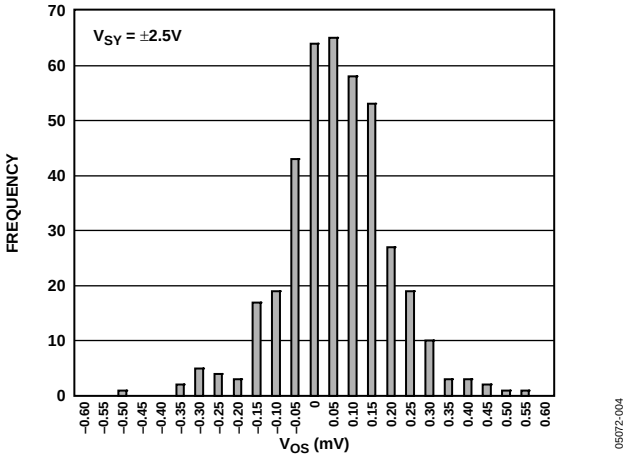



Figure 9. Input Offset Voltage

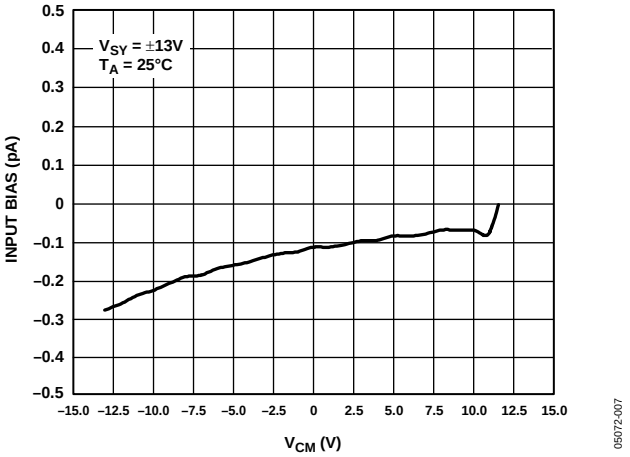



Figure 12. Input Bias Current vs. $V_{CM}$

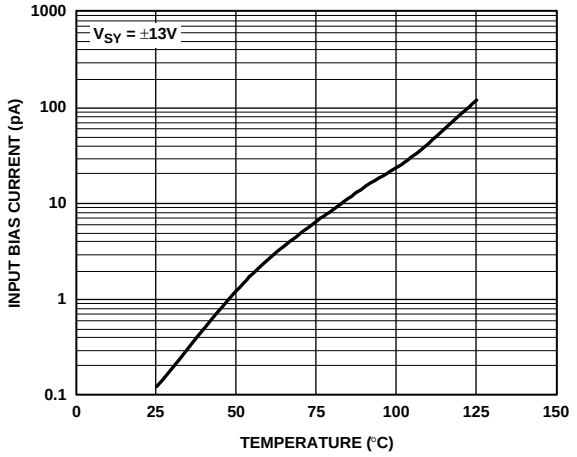



Figure 13. Input Bias Current vs. Temperature

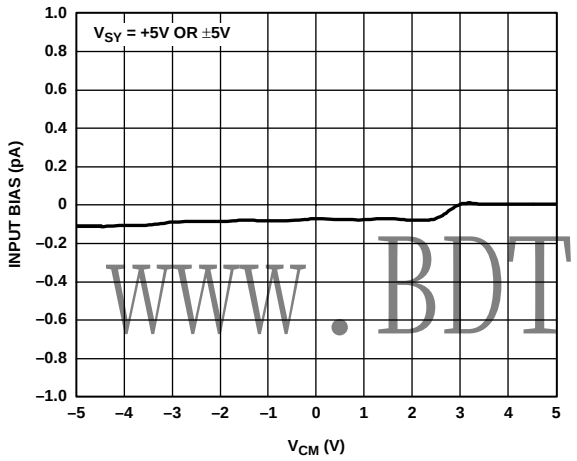



Figure 14. Input Bias Current vs. $V_{CM}$

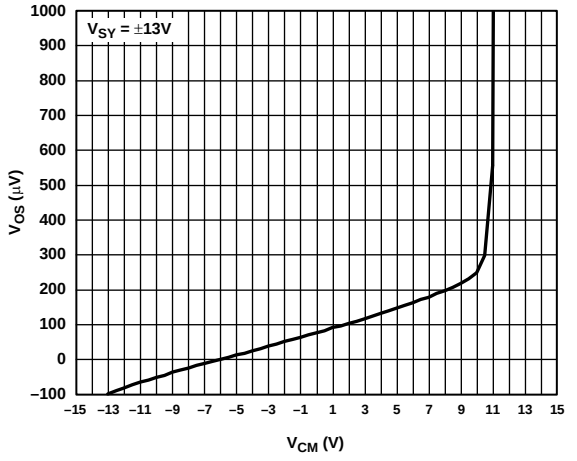



Figure 15. Input Offset Voltage vs. $V_{CM}$

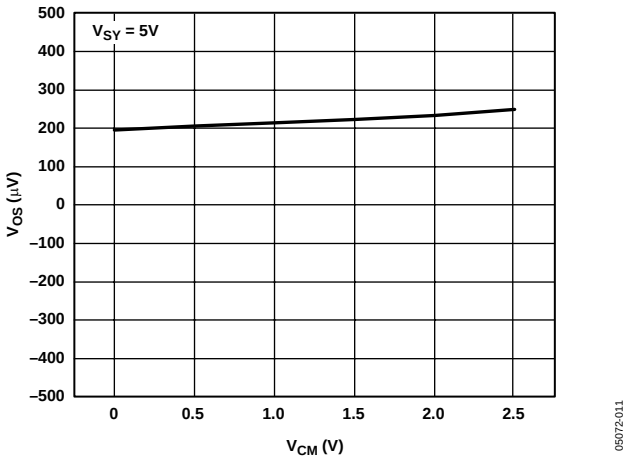



Figure 16. Input Offset Voltage vs. $V_{CM}$

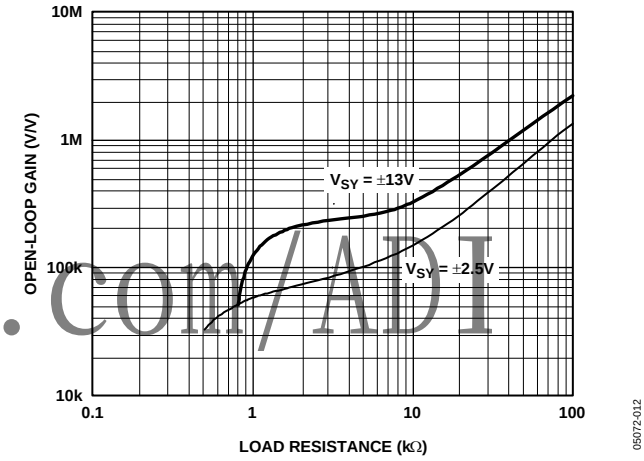



Figure 17. Open-Loop Gain vs. Load Resistance

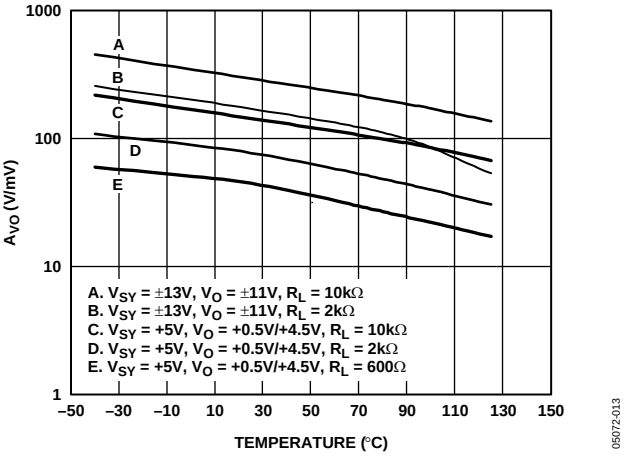



Figure 18. Open-Loop Gain vs. Temperature

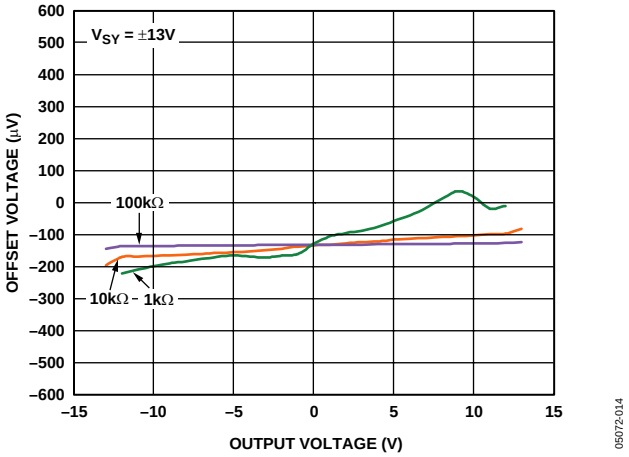



Figure 19. Input Error Voltage vs. Output Voltage for Resistive Loads

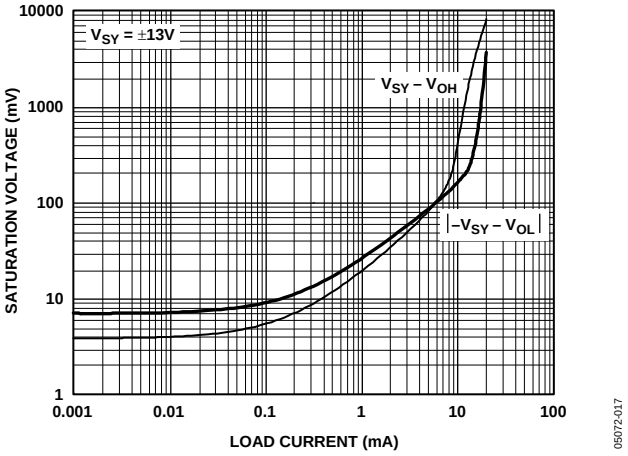



Figure 22. Output Saturation Voltage vs. Load Current

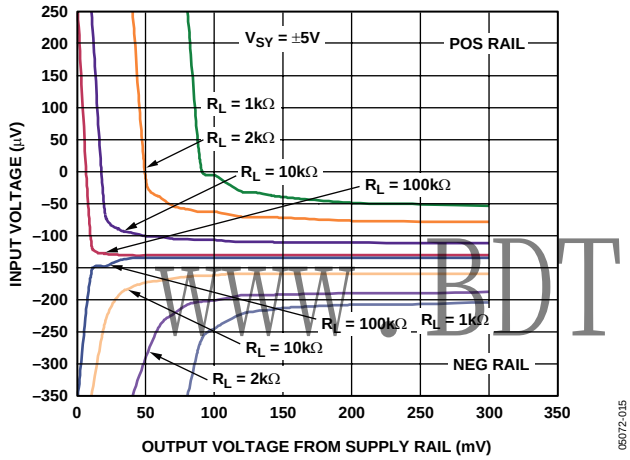



Figure 20. Input Error Voltage vs. Output Voltage Within 300 mV of Supply Rails

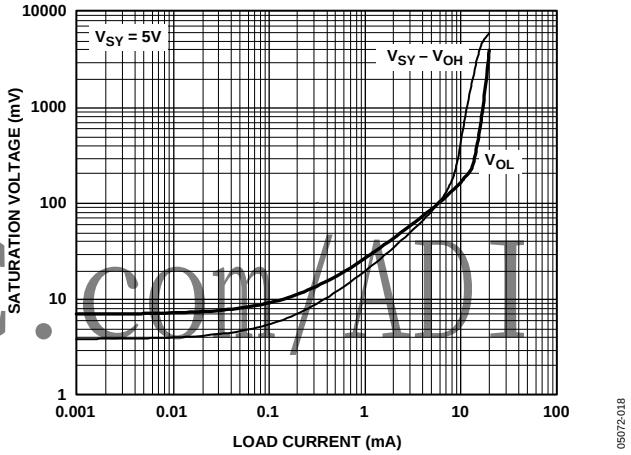
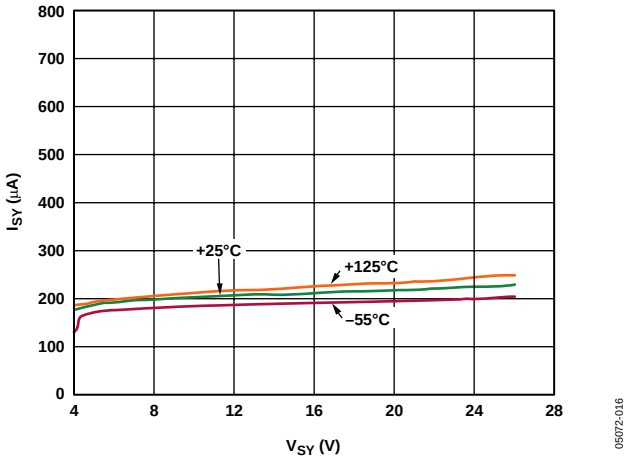



Figure 23. Output Saturation Voltage vs. Load Current

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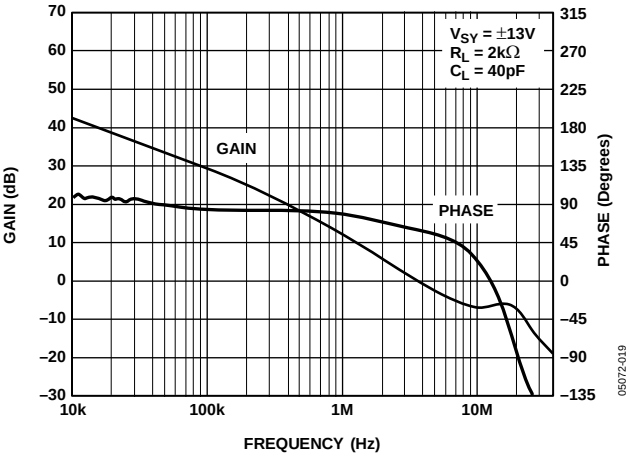



Figure 24. Open-Loop Gain and Phase Margin vs. Frequency

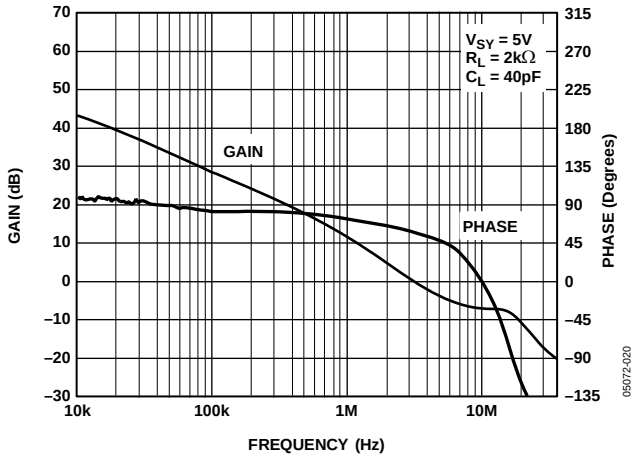



Figure 25. Open-Loop Gain and Phase Margin vs. Frequency

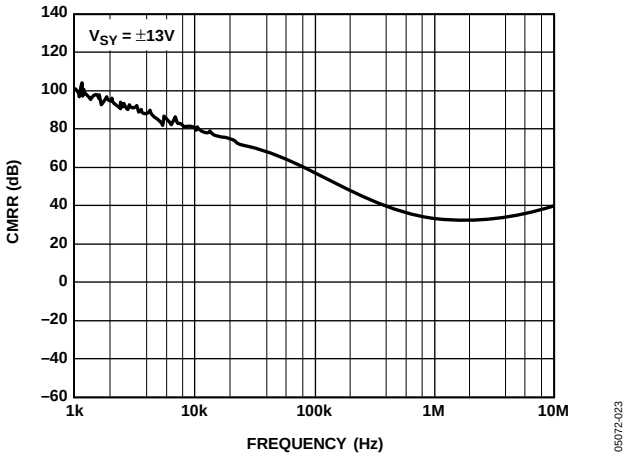



Figure 28. CMRR vs. Frequency

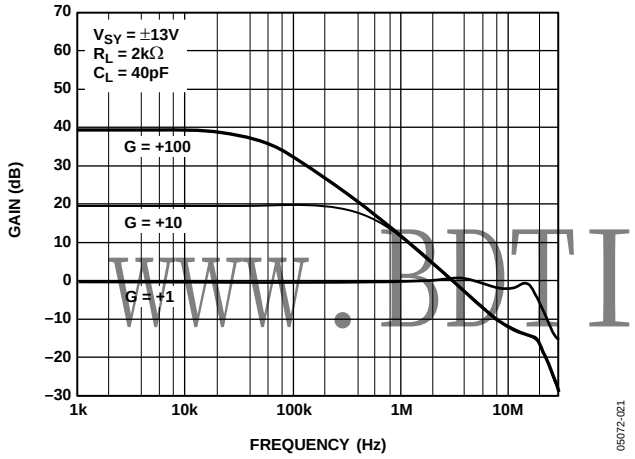



Figure 26. Closed-Loop Gain vs. Frequency

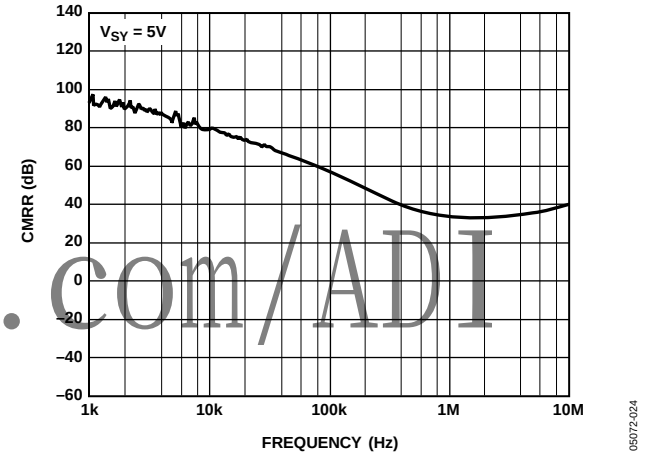



Figure 29. CMRR vs. Frequency

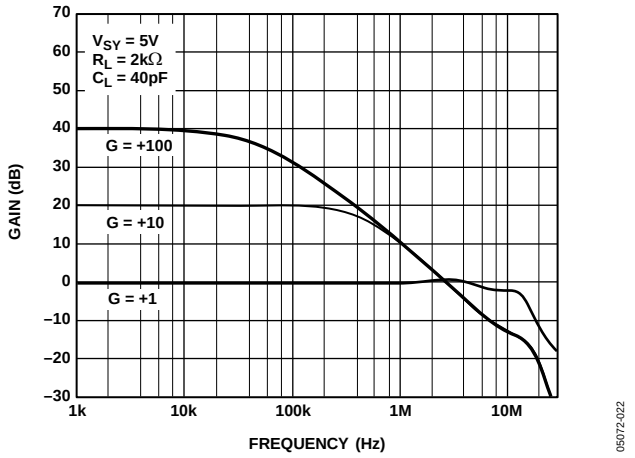



Figure 27. Closed-Loop Gain vs. Frequency

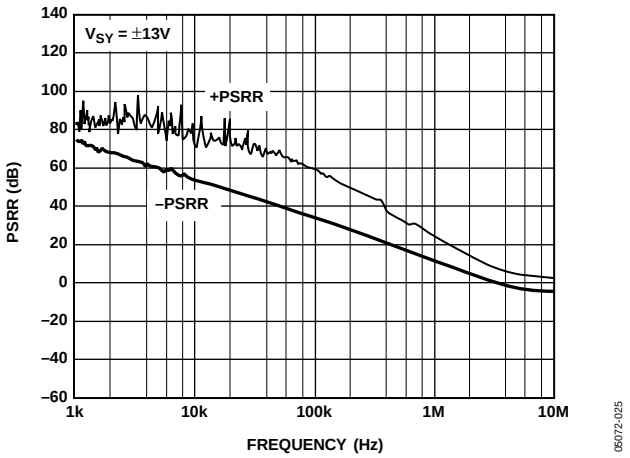



Figure 30. PSRR vs. Frequency

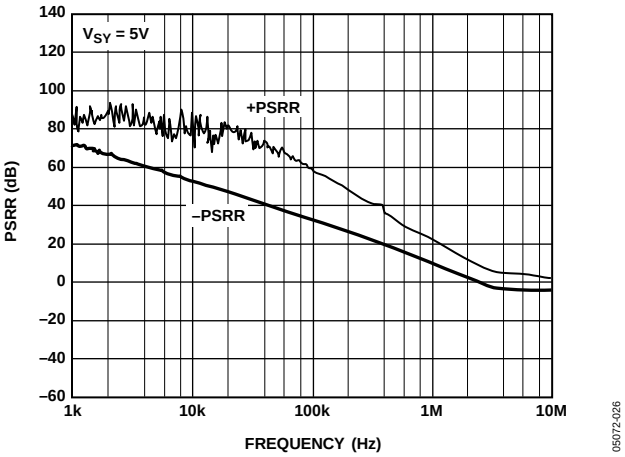



Figure 31. PSRR vs. Frequency

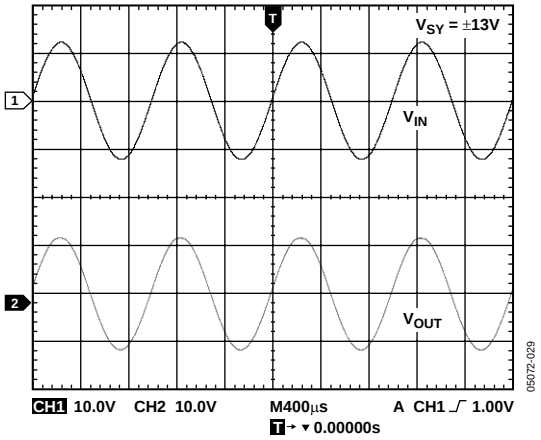



Figure 34. No Phase Reversal

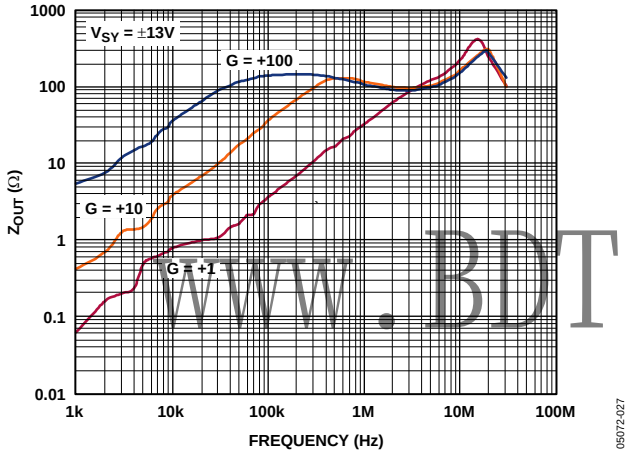



Figure 32. Output Impedance vs. Frequency

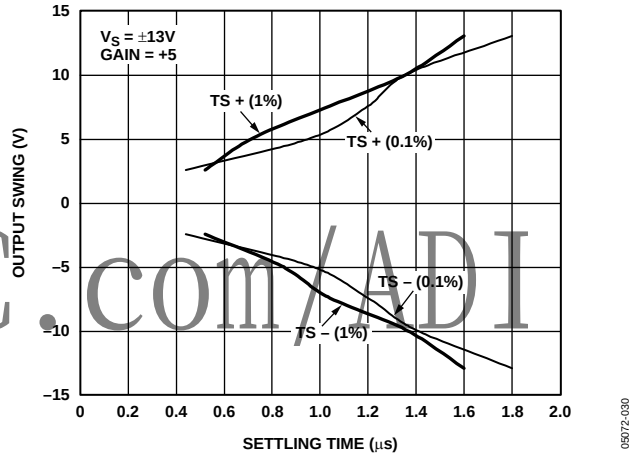



Figure 35. Output Swing and Error vs. Settling Time



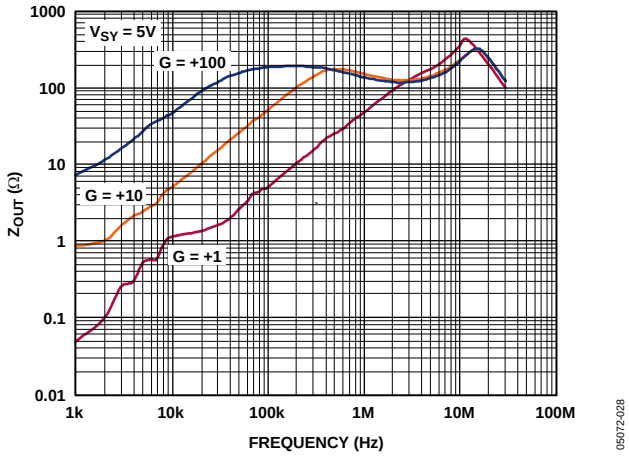



Figure 33. Output Impedance vs. Frequency

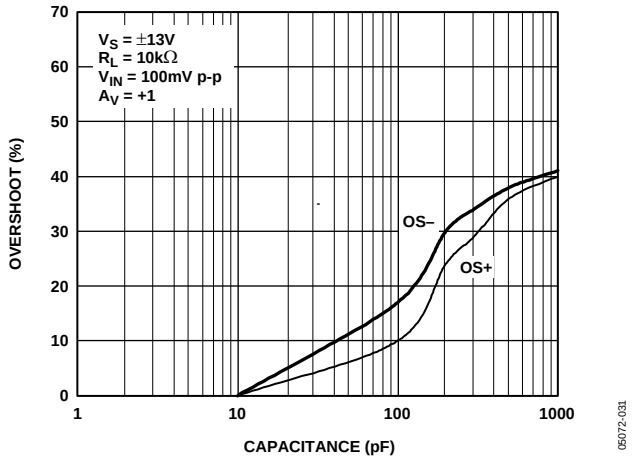



Figure 36. Small Signal Overshoot vs. Load Capacitance

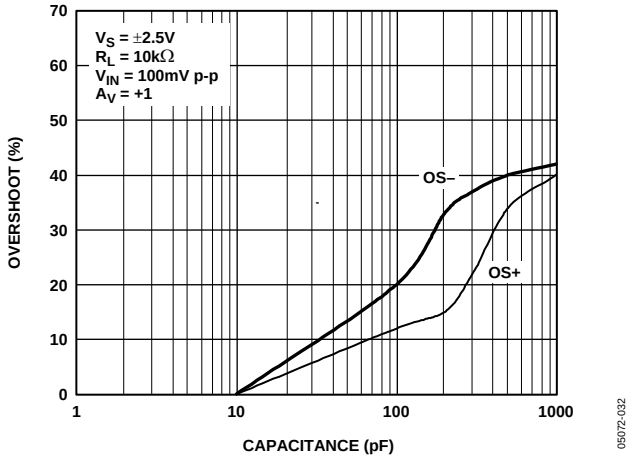



Figure 37. Small Signal Overshoot vs. Load Capacitance

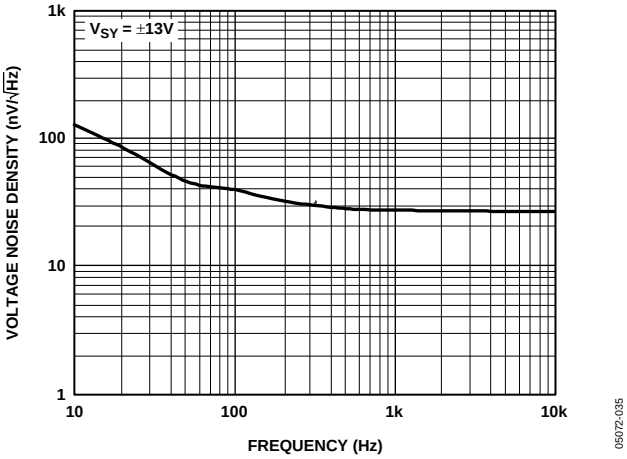



Figure 40. Voltage Noise Density

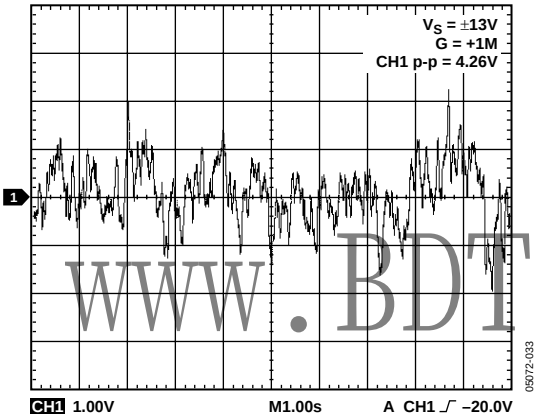



Figure 38. 0.1 Hz to 10 Hz Noise

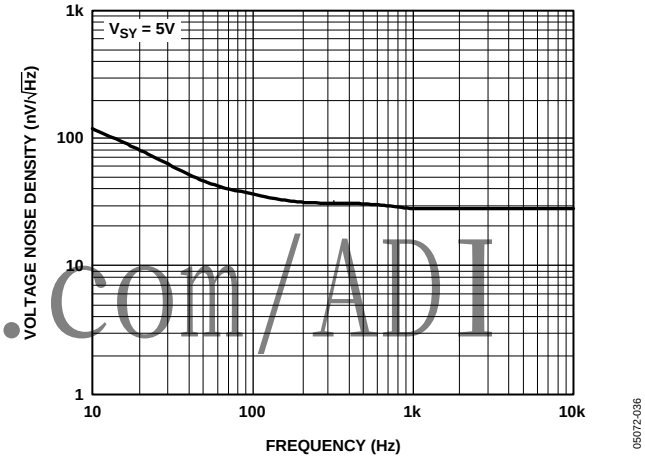



Figure 41. Voltage Noise Density



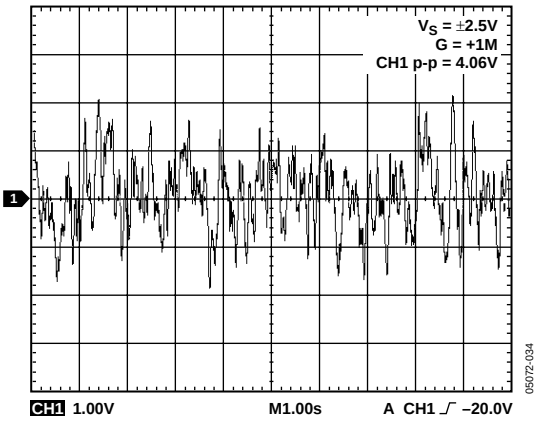



Figure 39. 0.1 Hz to 10 Hz Noise

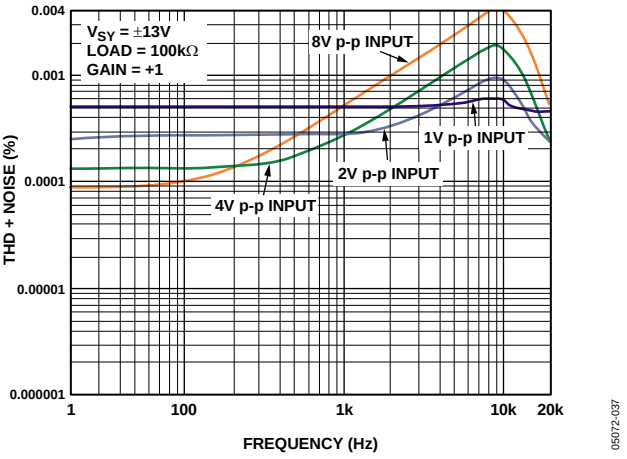



Figure 42. Total Harmonic Distortion + Noise vs. Frequency

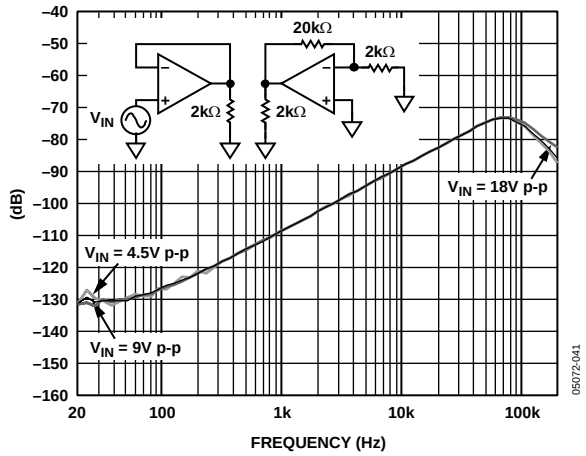
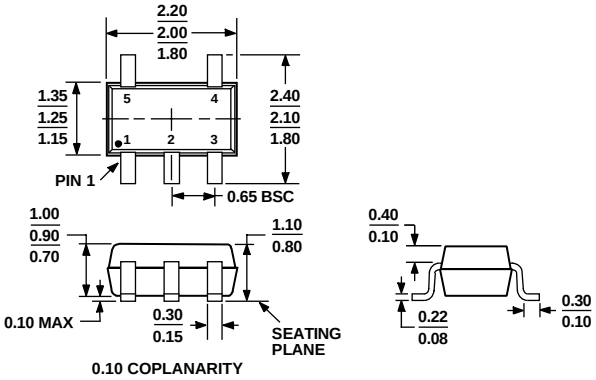


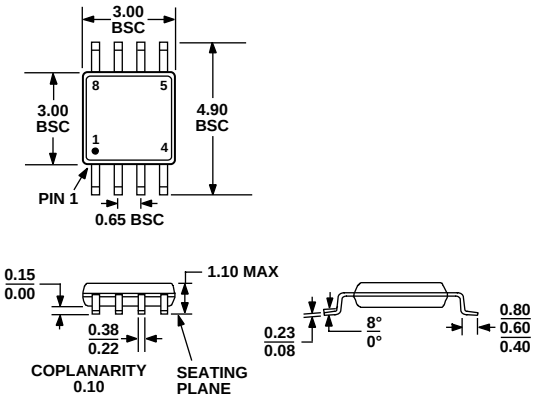

*Figure 43. Channel Separation*

# OUTLINE DIMENSIONS



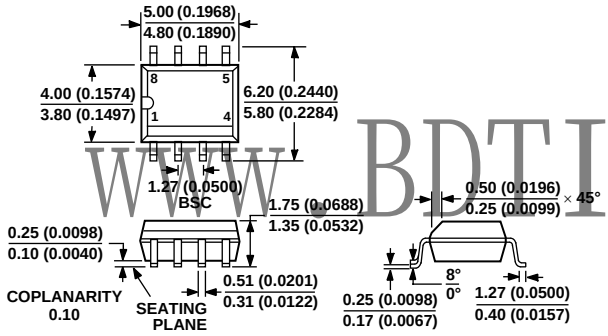

COMPLIANT TO JEDEC STANDARDS MO-203AA

*Figure 44. 5-Lead Thin Shrink Small Outline Transistor Package [SC70]*
*(KS-5)*
*Dimensions shown in millimeters*



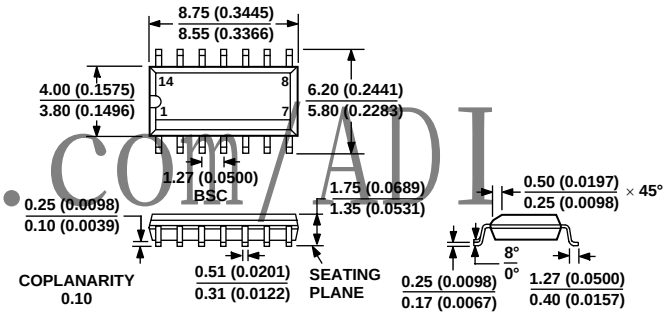

COMPLIANT TO JEDEC STANDARDS MO-187-AA

*Figure 46. 8-Lead Mini Small Outline Package [MSOP]*
*(RM-8)*
*Dimensions shown in millimeters*




COMPLIANT TO JEDEC STANDARDS MS-012-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

*Figure 45. 8-Lead Standard Small Outline Package [SOIC_N]*
*(R-8)*
*Dimensions shown in millimeters and (inches)*




COMPLIANT TO JEDEC STANDARDS MS-012-AB
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

*Figure 47. 14-Lead Standard Small Outline Package [SOIC_N]*
*(R-14)*
*Dimensions shown in millimeters and (inches)*

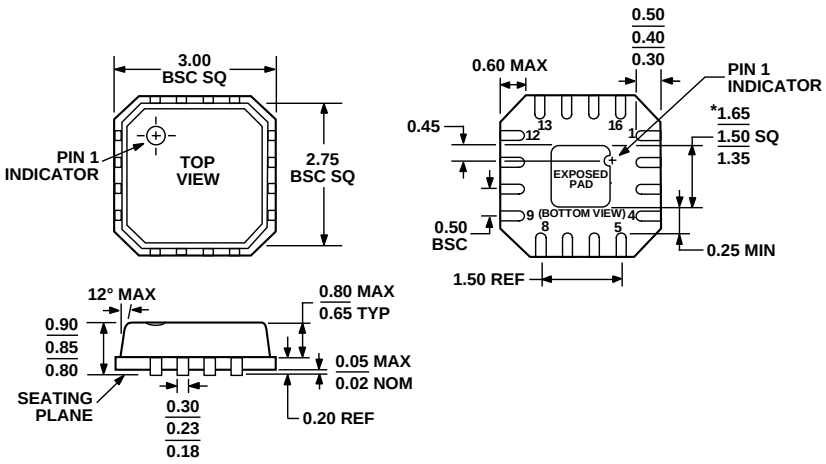



*Figure 48. 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ]*
*3 mm × 3 mm Body, Very Thin Quad (CP-16-3)*
*Dimensions shown in millimeters*

## ORDERING GUIDE

| Model | Temperature Range | Package Description | Package Option | Branding |
|---|---|---|---|---|
| AD8641AKSZ-R2[1] | –40°C to +125°C | 5-Lead SC70 | KS-5 | A07 |
| AD8641AKSZ-REEL7[1] | –40°C to +125°C | 5-Lead SC70 | KS-5 | A07 |
| AD8641AKSZ-REEL[1] | –40°C to +125°C | 5-Lead SC70 | KS-5 | A07 |
| AD8641ARZ[1] | –40°C to +125°C | 8-lead SOIC_N | R-8 | |
| AD8641ARZ-REEL7[1] | –40°C to +125°C | 8-lead SOIC_N | R-8 | |
| AD8641ARZ-REEL[1] | –40°C to +125°C | 8-lead SOIC_N | R-8 | |
| AD8642ARMZ-R2[1] | –40°C to +125°C | 8-lead MSOP | RM-8 | A0A |
| AD8642ARMZ-REEL[1] | –40°C to +125°C | 8-lead MSOP | RM-8 | A0A |
| AD8642ARZ[1] | –40°C to +125°C | 8-lead SOIC_N | R-8 | |
| AD8642ARZ-REEL7[1] | –40°C to +125°C | 8-lead SOIC_N | R-8 | |
| AD8642ARZ-REEL[1] | –40°C to +125°C | 8-lead SOIC_N | R-8 | |
| AD8643ARZ[1] | –40°C to +125°C | 14-lead SOIC_N | R-14 | |
| AD8643ARZ-REEL7[1] | –40°C to +125°C | 14-lead SOIC_N | R-14 | |
| AD8643ARZ-REEL[1] | –40°C to +125°C | 14-lead SOIC_N | R-14 | |
| AD8643ACPZ-R2[1] | –40°C to +125°C | 16-Lead LFCSP_VQ | CP-16-3 | AUA |
| AD8643ACPZ-REEL7[1] | –40°C to +125°C | 16-Lead LFCSP_VQ | CP-16-3 | AUA |
| AD8643ACPZ-REEL[1] | –40°C to +125°C | 16-Lead LFCSP_VQ | CP-16-3 | AUA |

[1] Z = Pb-free part.

## NOTES

## NOTES




D05072–0–4/05(B)